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3A, 45V - 60V Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Lower power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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 Trench Schottky barrier rectifier is designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters

MECHANICAL DATA

- Case: SOD-123HE
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.022g (approximately)

| KEY PARAMETERS | | | | | |
|--------------------|------------|------|--|--|--|
| PARAMETER | VALUE | UNIT | | | |
| I _{F(AV)} | 3 | Α | | | |
| V_{RRM} | 45 - 60 | ٧ | | | |
| I _{FSM} | 80 | Α | | | |
| T _{J MAX} | 150 | °C | | | |
| Package | SOD-123HE | | | | |
| Configuration | Single die | ! | | | |





SOD-123HE

| PARAMETER | SYMBOL | TSSE3U45 | TSSE3U60 | UNIT |
|---|--------------------|-------------|----------|------|
| Marking code on the device | | E3U45 | E3U60 | |
| Maximum repetitive peak reverse voltage | V _{RRM} | | | V |
| Working Peak Reverse Voltage | V _{RWM} | 45 | 60 | V |
| DC Blocking Voltage | V _{RM} | | | V |
| Maximum RMS voltage | V _{RMS} | 32 | 42 | V |
| Forward current | I _{F(AV)} | 3 | | Α |
| Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 80 | | А |
| Junction temperature | TJ | -55 to +150 | | °C |
| Storage temperature | T _{STG} | -55 to +150 | | °C |

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| THERMAL PERFORMANCE | | | | | | |
|--|------------------|-------|------|--|--|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | | | |
| Junction-to-lead thermal resistance per diode | R _{OJL} | 23 | °C/W | | | |
| Junction-to-ambient thermal resistance per diode | $R_{\Theta JA}$ | 70 | °C/W | | | |

| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | | |
|--|-----------|--|----------------|------|------|------|
| PARAMETER | PARAMETER | | | TYP | MAX | UNIT |
| | TSSE3U45 | $I_F = 1A, T_J = 25^{\circ}C$ | V _F | 0.33 | ı | V |
| | | $I_F = 3A, T_J = 25^{\circ}C$ | | 0.40 | 0.47 | V |
| | | $I_F = 1A, T_J = 125^{\circ}C$ | | 0.24 | ı | V |
| 5 | | I _F = 3A, T _J =125°C | | 0.34 | 0.44 | V |
| Forward voltage per diode (1) | TSSE3U60 | $I_F = 1A, T_J = 25^{\circ}C$ | | 0.39 | - | V |
| | | $I_F = 3A, T_J = 25^{\circ}C$ | | 0.49 | 0.58 | V |
| | | I _F = 1A, T _J =125°C | | 0.28 | - | V |
| | | I _F = 3A, T _J =125°C | | 0.43 | 0.52 | V |
| Reverse current @ rated V _R per diode (2) | | T _J = 25°C | 1 | ı | 1 | mA |
| neverse current @ rated v _R pe | ii uluue | T _J = 125°C | l _R | - | 50 | mA |

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

| ORDERING INFORMATION | | | | | | |
|----------------------|--------------------|-----------------|------------------------|-----------|-------------------|--|
| PART NO. | PART NO. SUFFIX | PACKING CODE | PACKING CODE SUFFIX | PACKAGE | PACKING | |
| TSSE3Uxx | Н | RV | G | SOD-123HE | 3,000 / 7" Reel | |
| (Note 1, 2) | П | RQ | G | SOD-123HE | 10,000 / 13" Reel | |

Notes:

- 1. "x" defines voltage from 45V (TSSE3U45) to 60V (TSSE3U60)
- 2. Whole series with green compound (halogen-free)

| EXAMPLE P/N | | | | | | |
|--------------|----------|--------------------|-----------------|------------------------|--------------------------------------|--|
| EXAMPLE P/N | PART NO. | PART NO. SUFFIX | PACKING CODE | PACKING CODE SUFFIX | DESCRIPTION | |
| TSSE3U45HRVG | TSSE3U45 | Н | RV | G | AEC-Q101 qualified Green compound | |

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

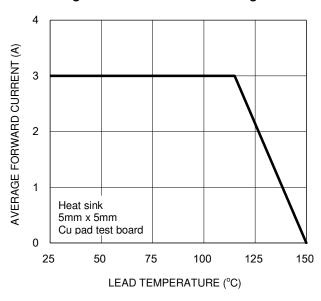


Fig.2 Typical Junction Capacitance

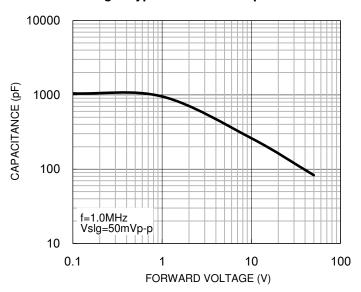


Fig.3 Typical Reverse Characteristics

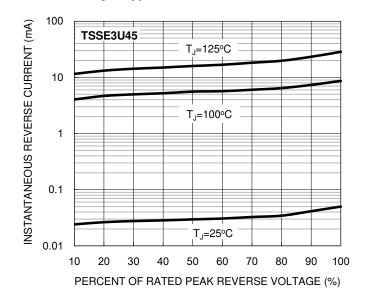
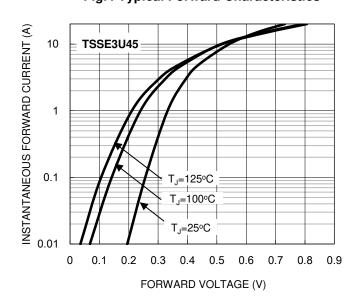


Fig.4 Typical Forward Characteristics





CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.5 Typical Reverse Characteristics

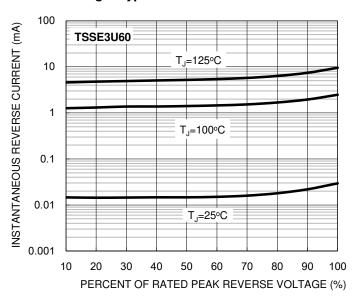
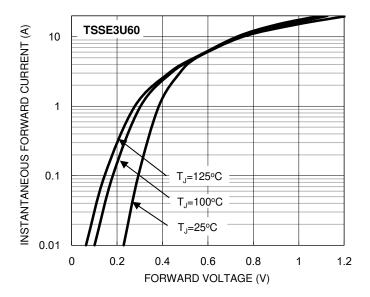


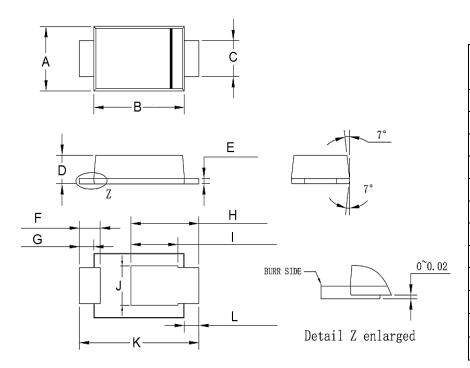
Fig.6 Typical Forward Characteristics





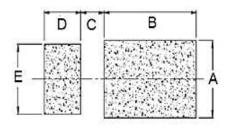
PACKAGE OUTLINE DIMENSIONS

SOD-123HE



| DIM | Unit | (mm) | Unit (inch) | | |
|------|------|------|-------------|-------|--|
| DIM. | Min | Max | Min | Max | |
| Α | 1.65 | 1.95 | 0.065 | 0.077 | |
| В | 2.60 | 3.00 | 0.102 | 0.118 | |
| С | 0.85 | 1.15 | 0.033 | 0.045 | |
| D | 0.75 | 0.85 | 0.030 | 0.033 | |
| E | 0.10 | 0.20 | 0.004 | 0.008 | |
| F | 0.55 | 0.75 | 0.022 | 0.030 | |
| G | 0.35 | 0.55 | 0.014 | 0.022 | |
| Н | 1.90 | 2.30 | 0.075 | 0.091 | |
| I | 1.35 | 1.55 | 0.053 | 0.061 | |
| J | 0.95 | 1.25 | 0.037 | 0.049 | |
| K | 3.50 | 3.90 | 0.138 | 0.154 | |
| L | 0.35 | 0.55 | 0.014 | 0.022 | |

SUGGESTED PAD LAYOUT



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| А | 1.40 | 0.055 |
| В | 2.40 | 0.094 |
| С | 0.70 | 0.028 |
| D | 0.90 | 0.035 |
| Е | 1.40 | 0.055 |

MARKING DIAGRAM



P/N = Marking Code YW = Date Code F = Factory Code



Taiwan Semiconductor

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